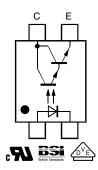




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# **Optocoupler, Photodarlington Output**





#### **FEATURES**

- High isolation test voltage 5300 V<sub>RMS</sub>
- Standard plastic DIP-4 package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





### **AGENCY APPROVALS**

- UL file no. E52744 system code H, double protection
- DIN EN 60747-5-2 (VDE 0884), IEC 60747-5-5
- DIN EN 60747-5-5 (VDE 0884) pending
- BSI IEC 60950; IEC 60065

#### **DESCRIPTION**

The SFH655A is optically coupled isolators with a gallium arsenide infrared LED and a silicon photodarlington detector. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits.

This optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

| ORDERING INFORMATION     |  |  |  |  |
|--------------------------|--|--|--|--|
| S F H 6 #                | # A - # # # # DIP Option 9  PACKAGE OPTION 7.62 mm > 0.1 mm  |  |  |  |
| TATT NOWBER              | The state of the s |  |  |  |
| AGENCY CERTIFIED/PACKAGE | CTR (%)  |  |  |  |
| cUL, VDE                 | > 600  |  |  |  |
| DIP-4                    | SFH655A  |  |  |  |
| SMD-4, option 9          | SFH655A-X009   |  |  |  |

#### Note

For additional information on the available options refer to option information

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                       |                   |       |       |  |  |
|--|-----------------------|-------------------|-------|-------|--|--|
| PARAMETER  | TEST CONDITION        | SYMBOL            | VALUE | UNIT  |  |  |
| INPUT  |                       |                   |       |       |  |  |
| Peak reverse voltage   |                       | V <sub>RM</sub>   | 6     | V     |  |  |
| Forward continuous current   |                       | I <sub>F</sub>    | 60    | mA    |  |  |
| Surge forward current  | t <sub>p</sub> ≤ 10µs | I <sub>FSM</sub>  | 2.5   | Α     |  |  |
| Derate linearly from 25 °C   |                       |                   | 1.33  | mW/°C |  |  |
| Power dissipation  |                       | P <sub>diss</sub> | 100   | mW    |  |  |
| OUTPUT   |                       |                   |       |       |  |  |
| Collector emitter breakdown voltage  |                       | BV <sub>CEO</sub> | 55    | V     |  |  |
| Emitter collector breakdown voltage  |                       | BV <sub>ECO</sub> | 6     | V     |  |  |
| Collector (load) current   |                       | I <sub>C</sub>    | 125   | mA    |  |  |
| Derate linearly from 25 °C   |                       |                   | 2     | mW/°C |  |  |
| Power dissipation  |                       | P <sub>diss</sub> | 150   | mW    |  |  |





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| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                  |             |       |  |  |
|---|---|------------------|-------------|-------|--|--|
| PARAMETER   | TEST CONDITION  | SYMBOL           | VALUE       | UNIT  |  |  |
| COUPLER   |   |                  |             |       |  |  |
| Derate linearly from 25 °C  |   |                  | 3.33        | mW/°C |  |  |
| Total power dissipation   |   | P <sub>tot</sub> | 250         | mW    |  |  |
| Storage temperature range   |   | T <sub>stg</sub> | -55 to +150 | °C    |  |  |
| Operating temperature range   |   | T <sub>amb</sub> | -55 to +100 | °C    |  |  |
| Soldering temperature (1)   | max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm | $T_{sld}$        | 260         | °C    |  |  |

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP)

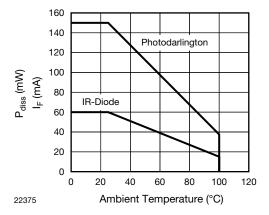


Fig. 1 - Power Dissipation vs. Ambient Temperature

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |         |                    |      |      |      |      |
|--|---|---------|--------------------|------|------|------|------|
| PARAMETER  | TEST CONDITION                            | PART    | SYMBOL             | MIN. | TYP. | MAX. | UNIT |
| INPUT  |   |         |                    |      |      |      |      |
| Forward voltage  | $I_F = 10 \text{ mA}$                     |         | $V_{F}$            | -    | 1.15 | 1.5  | V    |
| Reverse current  | V <sub>R</sub> = 6 V                      |         | I <sub>R</sub>     | -    | 0.02 | 10   | μA   |
| Capacitance  | $V_R = 0 V, f = 1 MHz$                    |         | Co                 | -    | 50   | -    | pF   |
| OUTPUT   |   |         |                    |      |      |      |      |
| Collector emitter breakdown voltage  | I <sub>CE</sub> = 100 μA                  |         | BV <sub>CEO</sub>  | 55   | -    | -    | V    |
| Emitter collector breakdown voltage  | $I_{EC} = 10 \mu A$                       |         | BV <sub>ECO</sub>  | 6    | -    | -    | V    |
| Collector emitter dark current   | $V_{CE} = 40 \text{ V}$                   |         | I <sub>CEO</sub>   | -    | 12   | 400  | nA   |
| Collector emitter capacitance  | $V_{CE} = 0 V$ , $f = 1 MHz$              |         | C <sub>CE</sub>    | -    | 13.5 | -    | pF   |
| COUPLER  |   |         |                    |      |      |      |      |
| Collector emitter saturation voltage   | $I_F = 20 \text{ mA}, I_C = 5 \text{ mA}$ | SFH655A | V <sub>CEsat</sub> | -    | -    | 1    | V    |
| Coupling capacitance   | V <sub>I-O</sub> = 0 V, f = 1 MHz         |         | C <sub>C</sub>     | -    | 0.45 | -    | pF   |

#### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements





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| CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |         |     |     |   |   |   |
|---|--|---------|-----|-----|---|---|---|
| PARAMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT                      |  |         |     |     |   |   |   |
| Current transfer ratio  | $I_F = 1 \text{ mA}, V_{CE} = 2 \text{ V}$ | SFH655A | CTR | 600 | - | - | % |

| SAFETY AND INSULATION RATINGS                           |  |                   |                    |           |
|---|--|-------------------|--------------------|-----------|
| PARAMETER   | TEST CONDITION   | SYMBOL            | VALUE              | UNIT      |
| Climatic classification                                 | According to IEC 68 part 1   |                   | 55 / 100 / 21      |           |
| Comparative tracking index                              |  | CTI               | 175                |           |
| Maximum rated withstanding isolation voltage            | t = 1 min  | V <sub>ISO</sub>  | 4420               | $V_{RMS}$ |
| Maximum transient isolation voltage                     |  | V <sub>IOTM</sub> | 10 000             | V         |
| Maximum repetitive peak isolation voltage               |  | V <sub>IORM</sub> | 890                | V         |
|   | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C                              | R <sub>IO</sub>   | ≥ 10 <sup>12</sup> | Ω         |
| Isolation resistance                                    | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C                             | R <sub>IO</sub>   | ≥ 10 <sup>11</sup> | Ω         |
| isolation registration                                  | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 150 °C<br>(construction test only) | R <sub>IO</sub>   | ≥ 10 <sup>9</sup>  | Ω         |
| Output safety power                                     |  | P <sub>SO</sub>   | 400                | mW        |
| Input safety current                                    |  | I <sub>SI</sub>   | 275                | mA        |
| Input safety temperature                                |  | T <sub>SI</sub>   | 175                | °C        |
| Creepage distance                                       | Standard DIP-4   |                   | ≥ 7                | mm        |
| Clearance distance                                      | Standard DIP-4   |                   | ≥ 7                | mm        |
| Insulation thickness                                    |  | DTI               | ≥ 0.4              | mm        |
| Partial discharge test voltage - routine test           | 100 %, t <sub>test</sub> = 1 s   | V <sub>pd</sub>   | 1.669              | kV        |
| Partial discharge test voltage - lot test (sample test) | $t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s}, (see fig. 2)$                 | V <sub>pd</sub>   | 1.424              | kV        |

#### Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits

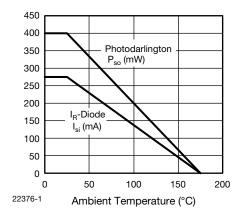


Fig. 2 - Derating Diagram

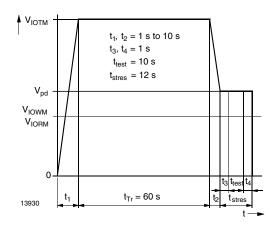


Fig. 3 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5



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| SWITCHING CHA                             | <b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |         |                  |      |      |      |      |
|---|---|---------|------------------|------|------|------|------|
| PARAMETER                                 | TEST CONDITION  | PART    | SYMBOL           | MIN. | TYP. | MAX. | UNIT |
| Turn-on time<br>(fig. 10, test circuit 1) | $V_{CC}$ = 10 V, $I_{C}$ = 2 mA, $R_{L}$ = 100 $\Omega$                                 | SFH612A | t <sub>on</sub>  |      | 16   |      | μs   |
| Turn-off time (fig. 10, test circuit 1)   | $V_{CC}$ = 10 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$                                     | SFH612A | t <sub>off</sub> |      | 15   |      | μs   |
| Rise time (fig. 10, test circuit 1)       | $V_{CC}$ = 10 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$                                     | SFH612A | t <sub>r</sub>   |      | 14   |      | μs   |
| Fall time<br>(fig. 10, test circuit 1)    | $V_{CC}$ = 10 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$                                     | SFH612A | t <sub>f</sub>   |      | 14   |      | μs   |
| Turn-on time (fig. 11, test circuit 2)    | $V_{CC}$ = 2 V, $I_C$ = 10 mA, $R_L$ = 100 $\Omega$                                     | SFH655A | t <sub>on</sub>  |      | 31   |      | μs   |
| Turn-off time (fig. 11, test circuit 2)   | $V_{CC}$ = 2 V, $I_C$ = 10 mA, $R_L$ = 100 $\Omega$                                     | SFH655A | t <sub>off</sub> |      | 55   |      | μs   |
| Rise time (fig. 11, test circuit 2)       | $V_{CC}$ = 2 V, $I_C$ = 10 mA, $R_L$ = 100 $\Omega$                                     | SFH655A | t <sub>r</sub>   |      | 27   | 250  | μs   |
| Fall time<br>(fig. 11, test circuit 2)    | $V_{CC}$ = 2 V, $I_C$ = 10 mA, $R_L$ = 100 $\Omega$                                     | SFH655A | t <sub>f</sub>   |      | 56   | 200  | μs   |

## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

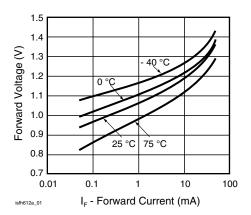


Fig. 4 - Forward Voltage vs. Forward Current

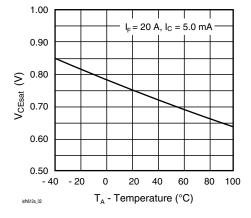


Fig. 5 - Collector Emitter Saturation Voltage vs. Temperature

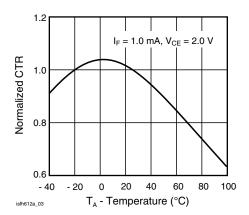


Fig. 6 - Normalized CTR vs. Temperature

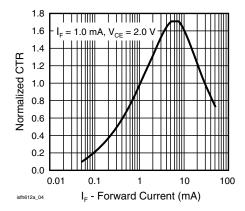


Fig. 7 - Normalized CTR vs. Forward Current



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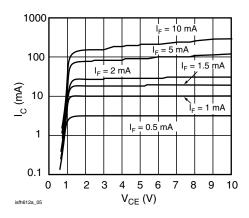


Fig. 8 - Collector Current vs. Collector Emitter Voltage

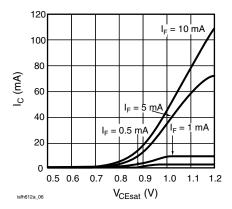


Fig. 9 - Collector Current vs. Collector Emitter Saturation Voltage

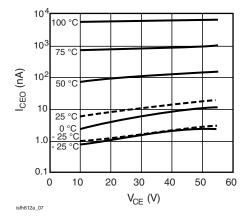


Fig. 10 - Collector Emitter Dark Current vs. Collector Emitter Voltage over Temperature

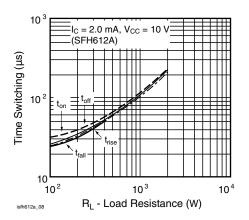


Fig. 11 - Switching Time vs. Load Resistor

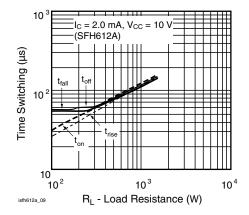


Fig. 12 - Switching Time vs. Load Resistor

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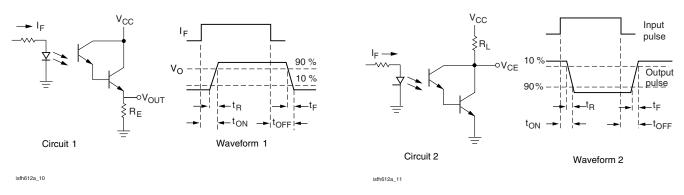
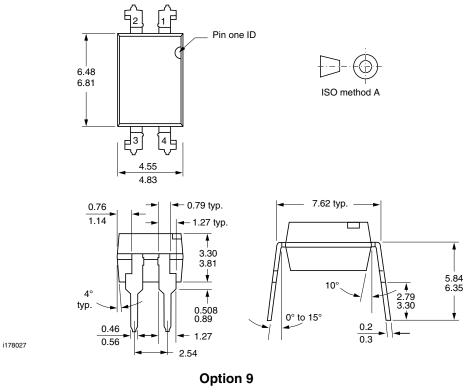
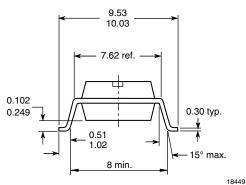


Fig. 13 - Switching Time Test Circuit and Waveforms

Fig. 14 - Switching Time Test Circuit and Waveforms

### **PACKAGE DIMENSIONS** in millimeters



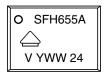




## SFH655A

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### **PACKAGE MARKING**



#### Note

• VDE logo is only printed on option 1 parts. Option information is not marked on the part



# **Footprint and Schematic Information**

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# Footprint and Schematic Information for SFH655A

The footprint and schematic symbols for the following parts can be accessed using the associated links. They are available in Eagle, Altium, KiCad, OrCAD / Allegro, Pulsonix, and PADS.

Note that the 3D models for these parts can be found on the Vishay product page.

| PART NUMBER  | FOOTPRINT / SCHEMATIC                               |
|--------------|---|
| SFH655A      | www.snapeda.com/parts/SFH655A/Vishay/view-part      |
| SFH655A-X009 | www.snapeda.com/parts/SFH655A-X009/Vishay/view-part |

For technical issues and product support, please contact optocoupleranswers@vishav.com.





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